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# FSB43004A Motion SPM<sup>®</sup> 45 LV Series

May 2015

### **Features**

- UL Certified No.E209204(UL1557)
- 40 V,  $R_{DS(ON)}$ =3.0 m $\Omega$ (max.) 3-phase MOSFET Inverter Module Including Control IC for Gate Drive and Protection.
- · Ceramic Substrate.

**Applications** 

- Three Separate Open-Emitter Pins from Low-Side MOSFETs for Three-Leg Current Sensing.
- · Single-Grounded Power Supply for Built-in HVIC.
- · Isolation Rating of 800 Vrms/min.

Motion Control - Home Appliance / Industrial Motor.

### **General Description**

FSB43004A is a Motion SPM® 45 LV module that Fairchild developed based on low-loss PowerTrench® MOSFET technology as a compact motor drive inverter solution for small power applications supplied by low voltage battery.



Figure 1. Packing Drawing ( Click to Activate 3D Content )

### **Package Marking and Ordering Information**

Device	Device Marking	Package	Packing Type	Quantity
FSB43004A	FSB43004A	SPMAA-A22	Rail	14

## **Integrated Power Functions**

• 40 V R<sub>DS(ON)</sub>= 2.1 mΩ(typ.) inverter for three-phase DC / AC power conversion (please refer to Figure 3)

## Integrated Drive, Protection, and System Control Functions

- For inverter high-side MOSFETs: gate drive circuit, high-voltage isolated high-speed level shifting, Under-Voltage Lock-Out (UVLO) Protection.
- For inverter low-side MOSFETs: gate drive circuit, Under-Voltage Lock-Out (UVLO) Protection.
- Fault signaling: corresponding to UV (low-side supply).
- Input interface: active-HIGH interface, works with 3.3 / 5 V logic, Schmitt-trigger input

## **Pin Configuration**

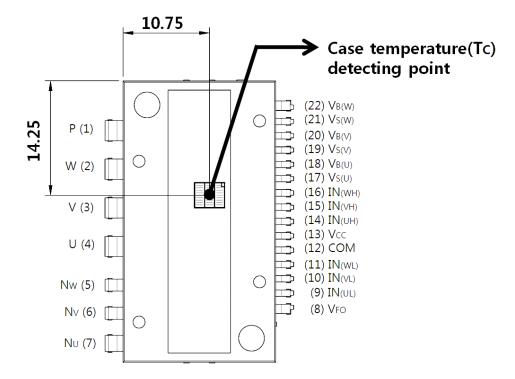


Figure 2.Top View

## **Pin Descriptions**

Pin Number	Pin Name	Pin Description
1	Р	Positive DC-Link Input
2	W	W Phase Output
3	V	V Phase Output
4	U	U Phase Output
5	N <sub>W</sub>	Negative DC-Link Input
6	N <sub>V</sub>	Negative DC-Link Input
7	N <sub>U</sub>	Negative DC-Link Input
8	V <sub>FO</sub>	Fault Output
9	IN <sub>(UL)</sub>	PWM Input for Low-Side U Phase MOSFET Drive
10	IN <sub>(VL)</sub>	PWM Input for Low-Side V Phase MOSFET Drive
11	IN <sub>(WL)</sub>	PWM Input for Low-Side W Phase MOSFET Drive
12	COM	Common Supply Ground
13	Vcc	Common Supply Voltage for IC and Low-side MOSFET Drive
14	IN <sub>(UH)</sub>	PWM Input for High-Side U Phase MOSFET Drive
15	IN <sub>(VH)</sub>	PWM Input for High-Side V Phase MOSFET Drive
16	IN <sub>(WH)</sub>	PWM Input for High-Side W Phase MOSFET Drive
17	V <sub>B(U)</sub>	Supply Voltage for High-Side U Phase MOSFET Drive
18	V <sub>S(U)</sub>	Supply Ground for High-Side U Phase MOSFET Drive
19	$V_{B(V)}$	Supply Voltage for High-Side V Phase MOSFET Drive
20	V <sub>S(V)</sub>	Supply Ground for High-Side V Phase MOSFET Drive
21	V <sub>B(W)</sub>	Supply Voltage for High-Side W Phase MOSFET Drive
22	V <sub>S(W)</sub>	Supply Ground for High-Side W Phase MOSFET Drive

## Internal Equivalent Circuit and Input/Output Pins

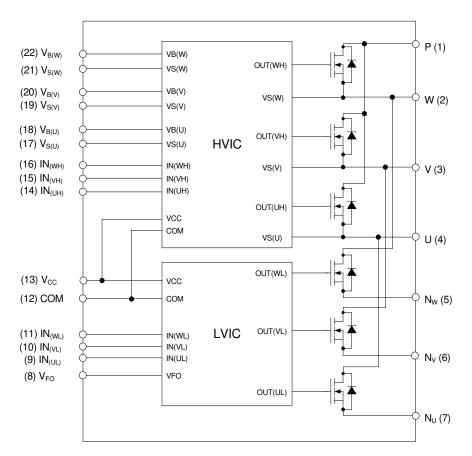


Figure 3. Internal Block Diagram

## **Absolute Maximum Ratings** (TJ = 25°C, unless otherwise specified.)

### **Inverter Part**

Symbol	Parameter	Conditions	Rating	unit
V <sub>PN</sub>	DC Link Input Voltage Drain-Source Voltage	Applied between P - N <sub>(U)</sub> , N <sub>(V)</sub> , N <sub>(W)</sub>	40	V
* ± I <sub>D</sub>	Drain Current	$T_C = 25$ °C, $T_J \le 150$ °C	71	Α
		$T_{C} = 100^{\circ}C, T_{J} \le 150^{\circ}C$	47	Α
* ± I <sub>DP</sub>	Peak Drain Current	$T_{C}$ = 25°C, under 1ms Pulse Width, $T_{J} \le$ 150°C	180	А
* P <sub>D</sub>	Maximum Power Dissipation	$T_C$ = 25°C, per Chip, $T_J \le 150$ °C	31	W
TJ	Operating Junction Temperature		-40 ~ 150	°C

### 1st Note:

### **Control Part**

Symbol	Parameter	Conditions	Rating	unit
V <sub>CC</sub>	Supply Voltage	Applied between V <sub>CC</sub> - COM	20	V
$V_{BS}$	Supply Voltage	$ \begin{array}{c} \text{Applied between } V_{B(U)} \text{ - } V_{S(U)}, \ V_{B(V)} \text{ - } V_{S(V)}, \\ V_{B(W)} \text{ - } V_{S(W)} \end{array} $	20	V
$V_{IN}$	PWM Signal Voltage	Applied between $IN_{(UH)}$ , $IN_{(VH)}$ , $IN_{(WH)}$ , $IN_{(WH)}$ , $IN_{(UL)}$ , $IN_{(VL)}$ , $IN_{(WL)}$ - COM	-0.3 ~ V <sub>CC</sub> +0.3	٧
$V_{FO}$	Fault Output Supply Voltage	Applied between V <sub>FO</sub> - COM	-0.3 ~ V <sub>CC</sub> +0.3	V
I <sub>FO</sub>	Fault Output Current	Sink Current at V <sub>FO</sub> Pin	1	mA

## **Total System**

Symbol	Parameter	Conditions	Rating	unit
T <sub>STG</sub>	Storage Temperature		-40 ~ 150	°C
V <sub>ISO</sub>	Isolation Voltage	60 Hz, Sinusoidal, AC 1 Minute, Connect Pins to Ceramic Substrate	800	V <sub>rms</sub>

## **Thermal Characteristics**

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
$R_{th(j-c)}$	Junction to Case Thermal Resistance	Inverter MOSFET part(per 1/6 module)	-	-	3.92	°C/W

<sup>1.</sup> Rating value of marking "\*" is calculation value or design factor.

## $\textbf{Electrical Characteristics} \ \, (TJ = 25^{\circ}C, \, unless \, otherwise \, specified.)$

### **Inverter Part**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>IN</sub> =0 V, I <sub>D</sub> =250 μA (2nd Notes 1)	40	-	-	V
R <sub>DS(ON)</sub>	Drain-Source ON Resistance	$V_{CC} = V_{BS} = 15 \text{ V}, V_{IN} = 5 \text{ V}, I_D = 60 \text{ A}$	-	2.1	3.0	mΩ
V <sub>SD</sub>	Source-Drain Diode Forward Voltage	$V_{CC} = V_{BS} = 15 \text{ V}, V_{IN} = 0 \text{ V}, I_{SD} = 60 \text{ A}$	-	0.8	-	V
t <sub>ON</sub>	Switching Characteristic	$V_{PN} = 20 \text{ V}, V_{CC} = V_{BS} = 15 \text{ V}, I_D = 60 \text{ A},$	-	1750	-	ns
t <sub>C(ON)</sub>		$V_{IN} = 0 \text{ V} \leftrightarrow 5 \text{ V}$ , High side, Inductive Load (2nd Notes 2)	-	900	-	ns
t <sub>OFF</sub>		(Zild Notes Z)	-	2600	-	ns
t <sub>C(OFF)</sub>			-	800	-	ns
t <sub>rr</sub>			-	60	-	ns
I <sub>rr</sub>			-	3	-	Α
t <sub>ON</sub>		$V_{PN} = 20 \text{ V}, V_{CC} = V_{BS} = 15 \text{ V}, I_D = 60 \text{ A},$	-	1900	-	ns
t <sub>C(ON)</sub>		$V_{IN} = 0 \text{ V} \leftrightarrow 5 \text{ V}$ , Low side, Inductive Load (2nd Notes 2)	-	850	-	ns
t <sub>OFF</sub>		(Zild Notes Z)	-	2600	-	ns
t <sub>C(OFF)</sub>			-	850	-	ns
t <sub>rr</sub>	]		-	60	-	ns
I <sub>rr</sub>	]		-	6	-	Α
I <sub>DSS</sub>	Drain-Source Leakage Current	$V_{DS} = V_{DSS}$	-	-	250	μΑ

#### 2nd Notes:

- 1. BV<sub>DSS</sub> is the absolute maximum voltage rating between drain and source terminal of each MOSFET. V<sub>PN</sub> should be sufficiently less than this value considering the effect of the stray inductance so that V<sub>DS</sub> should not exceed BV<sub>DSS</sub> in any case.
- 2.  $t_{ON}$  and  $t_{OFF}$  include the propagation delay time of the internal drive IC.  $t_{C(ON)}$  and  $t_{C(OFF)}$  are the switching time of MOSFET itself under the given gate driving condition internally. For the detailed information, please see Figure 4.

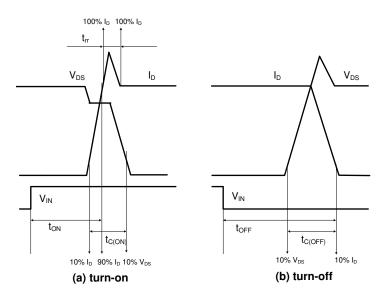


Figure 4. Switching Time Definition

### **Control Part**

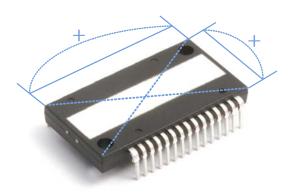
Symbol	Parameter	Co	nditions	Min.	Тур.	Max.	Unit
I <sub>QCC</sub>	Quiescent V <sub>CC</sub> Supply Current	V <sub>CC</sub> = 15 V, V <sub>IN</sub> = 0 V	V <sub>CC</sub> - COM	-	-	2.75	mA
I <sub>QBS</sub>	Quiescent V <sub>BS</sub> Supply Current	$V_{BS} = 15 \text{ V},$ $V_{IN} = 0 \text{ V}$	$egin{array}{c} V_{B(U)} - V_{S(U)}, \ V_{B(V)} - V_{S(V)}, \ V_{B(W)} - V_{S(W)} \end{array}$	-	-	0.3	mA
V <sub>FOH</sub>	Fault Output Voltage	10 kΩ to 5 V Pull-up	Normal	4.5	-	-	V
V <sub>FOL</sub>			Fault	-	-	0.5	V
UV <sub>CCD</sub>	Supply Circuit Under-	Detection Level		7.0	8.2	10.0	V
UV <sub>CCR</sub>	Voltage Protection	Reset Level		8.0	9.4	11.0	V
UV <sub>BSD</sub>		Detection Level		7.0	8.0	9.5	V
UV <sub>BSR</sub>		Reset Level		8.0	9.0	10.5	V
t <sub>FOD</sub>	Fault-Out Pulse Width			30	-	-	μS
V <sub>IN(ON)</sub>	ON Threshold Voltage	Applied between $IN_{(UH)}$ , $IN_{(VH)}$ , $IN_{(WH)}$ , $IN_{(UL)}$ ,		-	-	2.6	V
V <sub>IN(OFF)</sub>	OFF Threshold Voltage	IN <sub>(VL)</sub> , IN <sub>(WL)</sub> - COM		0.8	-	-	V

## **Recommended Operating Conditions**

Cymbol	Parameter	Conditions	Value			Unit
Symbol	Parameter	Conditions		Тур.	Max.	Ollit
V <sub>PN</sub>	Supply Voltage	Applied between P - N <sub>(U)</sub> , N <sub>(V)</sub> , N <sub>(W)</sub>	-	20	-	V
V <sub>CC</sub>	Control Supply Voltage	Applied between V <sub>CC</sub> - COM	13.5	15	16.5	V
V <sub>BS</sub>	Control Supply Voltage	Applied between $V_{B(U)}$ - $V_{S(U)}$ , $V_{B(V)}$ - $V_{S(V)}$ , $V_{B(W)}$ - $V_{S(W)}$	13.0	15	18.5	V
dV <sub>CC</sub> /dt, dV <sub>BS</sub> /dt	Control Supply Variation		-1	-	1	V/μs
V <sub>SEN</sub>	Voltage for Current Sensing	Applied between N <sub>U</sub> , N <sub>V</sub> , N <sub>W</sub> - COM (Including surge voltage)	-4	-	4	V

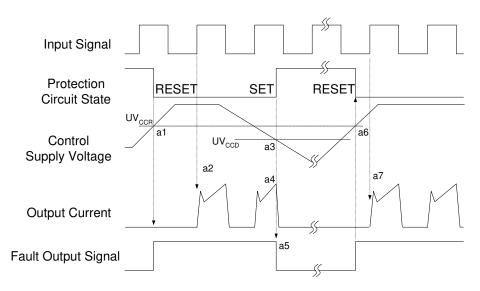
## **Mechanical Characteristics and Ratings**

Parameter	Cor	nditions	Limits			Units
Parameter	Col	Ullullions		Тур.	Max.	Ullits
Mounting Torque	Mounting Screw: - M3		0.51	0.62	0.72	N•m
Device Flatness		See Figure 5	-	-	120	μm
Weight			-	8.4	-	g



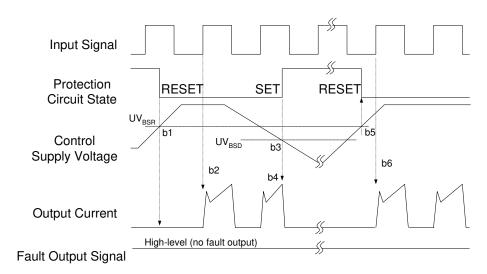
**Figure 5. Flatness Measurement Position** 

### **Time Charts of Protective Function**



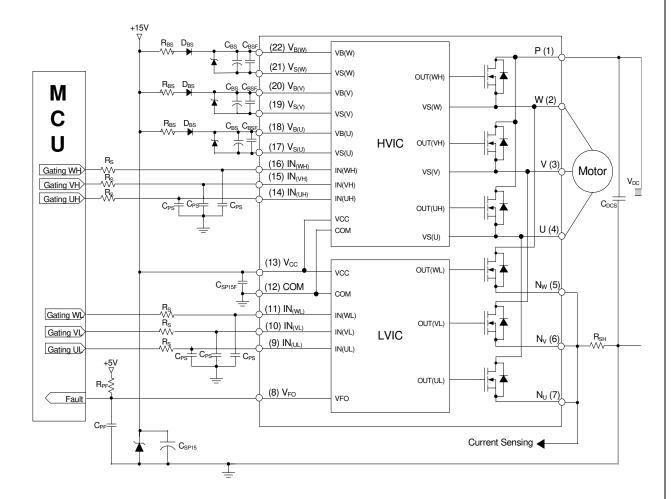
- a1 : Control supply voltage rises: after the voltage rises UV<sub>CCR</sub>, the circuits start to operate when the next input is applied.
- a2: Normal operation: MOSFET ON and carrying current.
- a3 : Under-Voltage detection (UV<sub>CCD</sub>).
- a4 : MOSFET OFF in spite of control input condition.
- a5 : Fault output operation starts.
- a6 : Under-Voltage reset (UV $_{CCR}$ ).
- a7: Normal operation: MOSFET ON and carrying current.

Figure 6. Under-Voltage Protection (Low-side)



- b1 : Control supply voltage rises: after the voltage reaches UV<sub>BSR</sub>, the circuits start to operate when the next input is applied.
- b2: Normal operation: MOSFET ON and carrying current.
- b3: Under-Voltage detection (UV<sub>BSD</sub>).
- b4 : MOSFET OFF in spite of control input condition, but there is no fault output signal.
- b5 : Under-Voltage reset (UV<sub>BSB</sub>).
- b6: Normal operation: MOSFET ON and carrying current

Figure 7. Under-Voltage Protection (High-side)

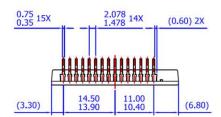


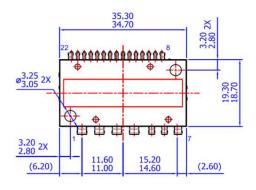
#### 3rd Notes:

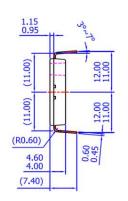
- 1. To avoid malfunction, the wiring of each input should be as short as possible. (less than  $2\sim3$  cm)
- 2. V<sub>FO</sub> output is open drain type. This signal line should be pulled up to the positive side of the MCU or control power supply with a resistor that makes IFO up to 1 mA.
- 3. Input signal is High-Active type. There is a 5 kQ resistor inside the IC to pull down each input signal line to GND. RC coupling circuits is recommended for the prevention of input signal oscillation. R<sub>F</sub>C<sub>F</sub> constant should be selected in the range 50~150ns. (Recommended R<sub>S</sub>=100  $\Omega$  , C<sub>PS</sub>=1 nF)
- 4. Each capacitors should be mounted as close to the SPM® pins as possible.
- 5. Relays are used at almost every systems of electrical equipment of home appliances. In these cases, there should be sufficient distance between the CPU and the relays.
- 6. The zener diode should be adopted for the protection of ICs from the surge destruction between each pair of control supply terminals. (Recommended zener diode=24 / 1 W)

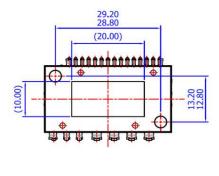
**Figure 8. Typical Application Circuit** 

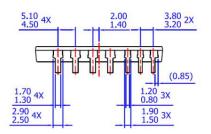
## **Detailed Package Outline Drawings**

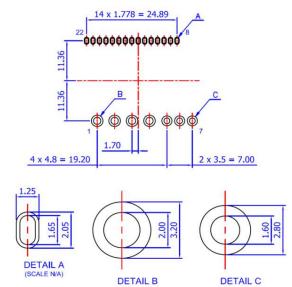












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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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